Document Number: MHW1304L
Rev. 3, 1/2001

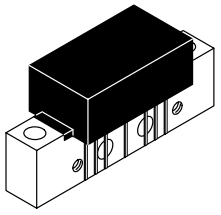
Low Distortion Wideband Reverse Amplifier Module

Designed specifically for broadband applications requiring low distortion characteristics. Specified for use as return amplifiers for low-split 2-way cable TV systems. Features all gold metallization system.

- Guaranteed Broadband Power Gain
- Guaranteed Broadband Noise Figure
- Superior Gain, Return Loss and DC Current Stability with Temperature
- All Gold Metallization
- Circuit Design Optimized for Good RF Stability Under High VSWR Load Conditions
- Transformers Designed to Ensure Good Low Frequency Gain Stability versus Temperature

MHW1304L

30 dB
50 MHz
24 Vdc
CATV LOW CURRENT AMPLIFIER



CASE 1302-01, STYLE 1

ARCHIVE INFORMATION

Table 1. Maximum Ratings*

Parameter	Symbol	Value	Unit
DC Supply Voltage	V_{CC}	+28	Vdc
RF Input Voltage (Single Tone)	V_{IN}	+70	dBmV
Operating Case Temperature Range	T_C	- 20 to +100	°C
Storage Temperature Range	T_{stg}	- 40 to +100	°C

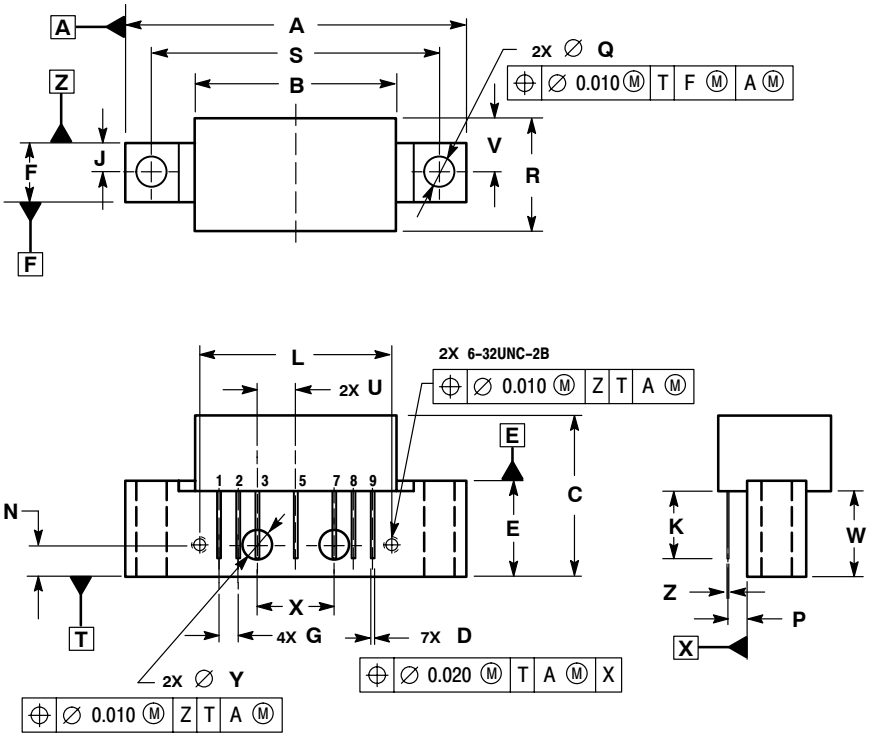
Table 2. Electrical Characteristics (V_{CC} = 24 Vdc, T_C = 30°C, 75 ohm system, unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
Bandwidth	All	BW	5.0	50	MHz
Power Gain	(f = 5.0 MHz)	Gp	29.2	30.8	dB
Slope	(f = 50-65 MHz)	S	-0.2	—	dB
Return Loss	(@ f = 5.0-50 MHz) (@ f = 65 MHz)	RL	18 16	— —	dB
Second Order Distortion	(V_{out} = +50 dBmV/ch)	IMD	—	-70	dBc
Cross Modulation	(V_{out} = +50 dBmV/ch)	XMD_4	—	-57	dBc
Triple Beat Distortion	(V_{out} = +50 dBmV/ch)	TB_3	—	-66	dBc
Noise Figure	(f = 50 MHz)	NF	—	4.5	dB
DC Current		I_{DC}	100	135	mA

NOTES

ARCHIVE INFORMATION

PACKAGE DIMENSIONS



NOTES:
1. DIMENSIONS ARE IN INCHES.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	---	1.775	---	45.085
B	---	1.085	---	27.559
C	---	0.840	---	21.336
D	0.015	0.021	0.381	0.533
E	0.465	0.510	11.811	12.954
F	0.300	0.325	7.62	8.255
G	0.100 BSC		2.540 BSC	
J	0.156 BSC		3.962 BSC	
K	0.315	0.355	8.001	9.017
L	1.000 BSC		25.400 BSC	
N	0.165 BSC		4.191 BSC	
P	0.100 BSC		2.540 BSC	
Q	0.148	0.168	3.759	4.267
R	---	0.600	---	15.24
S	1.500 BSC		38.100 BSC	
U	0.200 BSC		5.080 BSC	
V	---	0.250	---	6.350
W	0.435	---	11.049	---
X	0.400 BSC		10.160 BSC	
Y	0.152	0.163	3.861	4.140
Z	0.009	0.011	0.229	0.279

STYLE 1:
PIN 1. RF INPUT
2. GROUND
3. GROUND
4. DELETED
5. VDC
6. DELETED
7. GROUND
8. GROUND
9. RF OUTPUT

CASE 1302-01
ISSUE B

ARCHIVE INFORMATION

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